MCH6431

Power MOSFET 30V, 55mΩ, 5A, Single N-Channel



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Features

- Low On-Resistance
- 4V Drive
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance

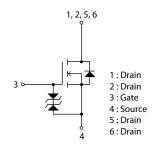
VDSS	R _{DS} (on) Max	ID Max	
	55mΩ@ 10V		
30V	91mΩ@ 4.5V	5A	
	109mΩ@ 4V		

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	30	V
Gate to Source Voltage	VGSS	±20	٧
Drain Current (DC)	ID	5	Α
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	IDP	20	А
Power Dissipation When mounted on ceramic substrate (1200mm² × 0.8mm)	PD	1.5	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	–55 to +150	°C

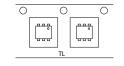
Electrical Connection N-Channel



Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient			
When mounted on ceramic substrate	$R_{\theta JA}$	83.3	°C/W
(1200mm ² × 0.8mm)			

Packing Type: TL Marking





Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

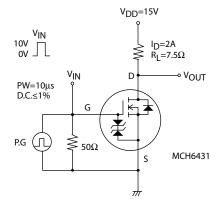
MCH6431

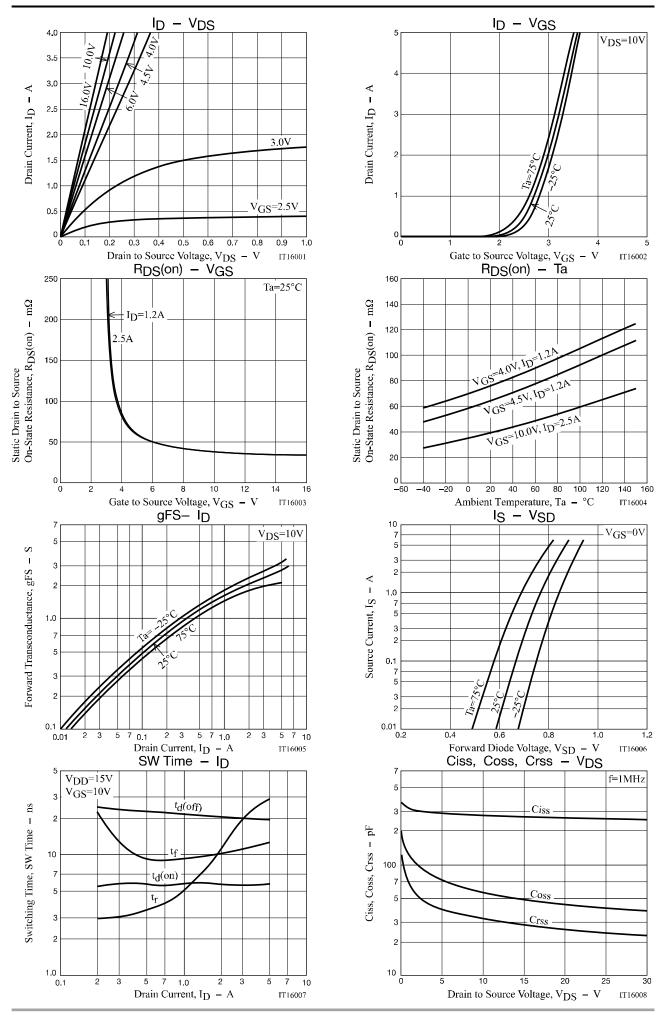
Electrical Characteristics at Ta = 25°C

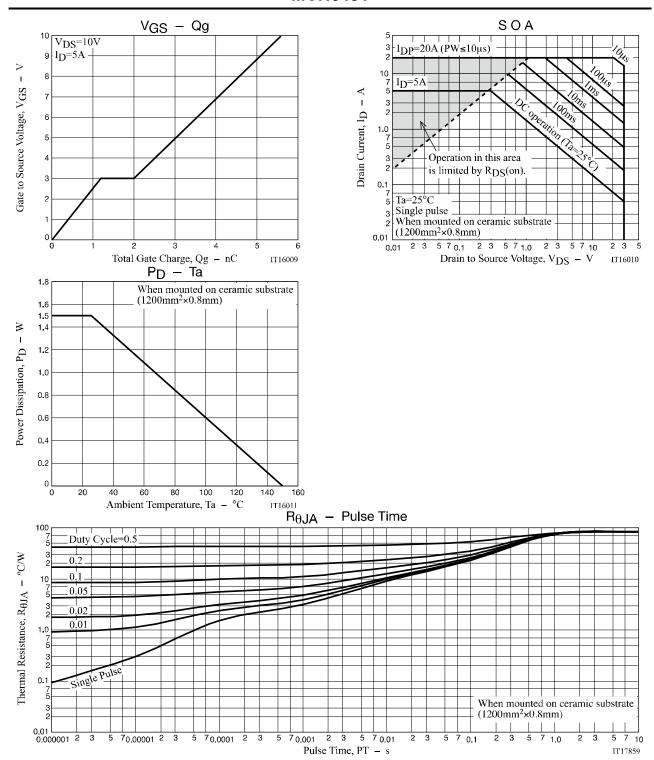
Parameter	Committee of	Conditions	Value			Unit
Parameter	Symbol		min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =10V, I _D =1mA	1.2		2.6	٧
Forward Transconductance	9FS	V _{DS} =10V, I _D =2.5A		2.2		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =2.5A, V _{GS} =10V		42	55	mΩ
	R _{DS} (on)2	I _D =1.2A, V _{GS} =4.5V		65	91	mΩ
	R _{DS} (on)3	I _D =1.2A, V _{GS} =4V		78	109	mΩ
Input Capacitance	Ciss			280		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		60		pF
Reverse Transfer Capacitance	Crss			30		pF
Turn-ON Delay Time	t _d (on)			5.7		ns
Rise Time	t _r	On a constitut Total City II		11		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		21		ns
Fall Time	tf			10		ns
Total Gate Charge	Qg			5.6		nC
Gate to Source Charge	Qgs	V _{DS} =15V, V _{GS} =10V, I _D =5A		1.2		nC
Gate to Drain "Miller" Charge	Qgd			0.8		nC
Forward Diode Voltage	V _{SD}	I _S =5A, V _{GS} =0V		0.85	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit







Package Dimensions

MCH6431-TL-H / MCH6431-TL-W

MCPH6

CASE 419AS ISSUE O

unit: mm

1: Drain

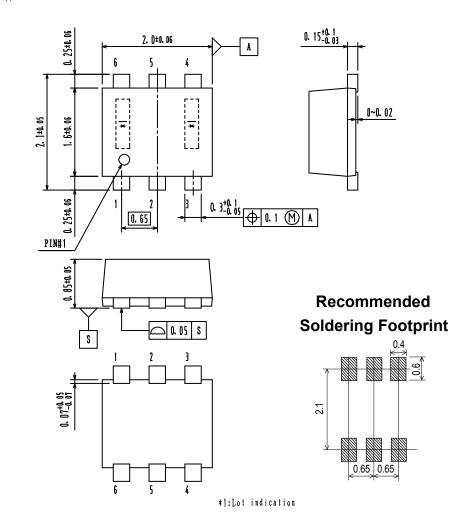
2: Drain

3: Gate

4 : Source

5: Drain

6: Drain



ORDERING INFORMATION

Device	Package	Shipping	Note
MCH6431-TL-H	MCPH6	MCPH6 3,000 pcs. / Tape & Reel Pb	Pb-Free
MCH6431-TL-W	SC-88FL,SC-70-6,SOT-363	3,000 pcs. / Tape & Neel	and Halogen Free

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage: Since the MCH6431 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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